Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inche	s and 0.260 inches
Terminal Length:	
Between 1.500 inche	s and 1.750 inches
Overall Diameter:	
Between 0.335 inche	s and 0.370 inches
Internal Configurati	on:
Junction contact	
Electrode Internally	-electrically Connected To Case:
Anode	
Mounting Method:	
Terminal	
Terminal Circle Dia	neter:
0.200 inches	
Features Provided:	
Hermetically sealed	case
Semiconductor Mat	erial:
Silicon	
Voltage Rating In V	olts Per Characteristic:
2.2 forward voltage,	peak and 0.9 gate trigger voltage, dc and 200.0 reverse voltage, peak
Current Rating Per	Characteristic:
75.00 microamperes	forward current, total rms preset and 220.00 milliamperes forward current, total rms megahertz
Maximum Operatin	g Tempurature Per Measurement Point:
125.0 degrees celsiu	s ambient air
Special Features:	
Junction pattern arra	ngement: pnpn
Test Data Documer	t:
81349-mil-s-19500 s	pecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes co	nmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and p	erformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	Quantity:
3 uninsulated wire le	ad
Specification Data:	
81349-mil-s-19500/2	76 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	

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